

*February 2015*

**Applied Nanotech, Inc.** A PEN Inc. Company

Technology of Mind Over Matter

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## Applied Nanotech at a Glance

3006 Longhorn Blvd., Suite 107  
Austin, TX 78758

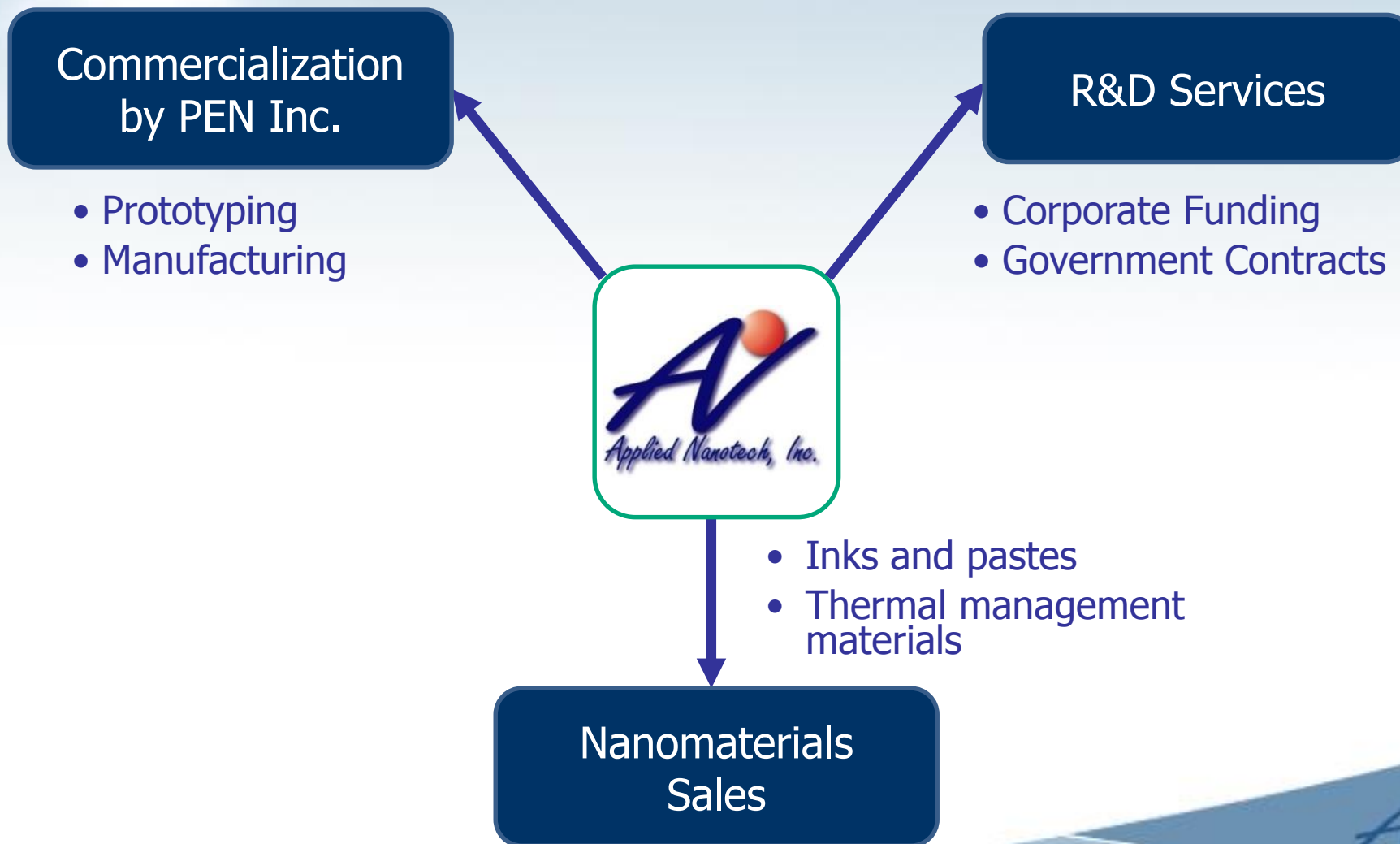


# ANI Introduction



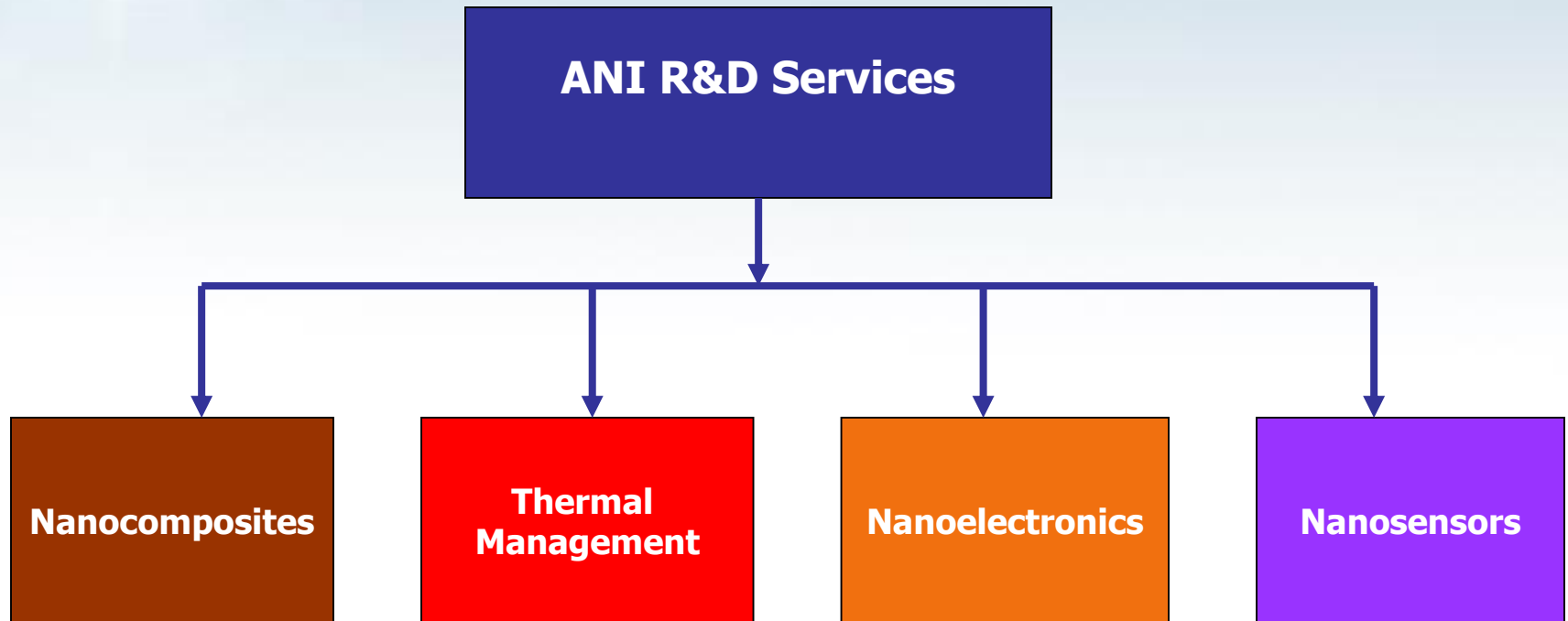
- Located in Austin, Texas USA
- Founded in 1988
- Nanotechnology R&D with emphasis in:
  - 1) Thermal Management
  - 2) Nanocomposites
  - 3) Nanoelectronics
  - 4) Nanosensors
- Three pronged business model:
  - 1) R&D Services
  - 2) Product Prototyping for PEN Inc.
  - 3) Nanomaterials Sales

# ANI's Business Model

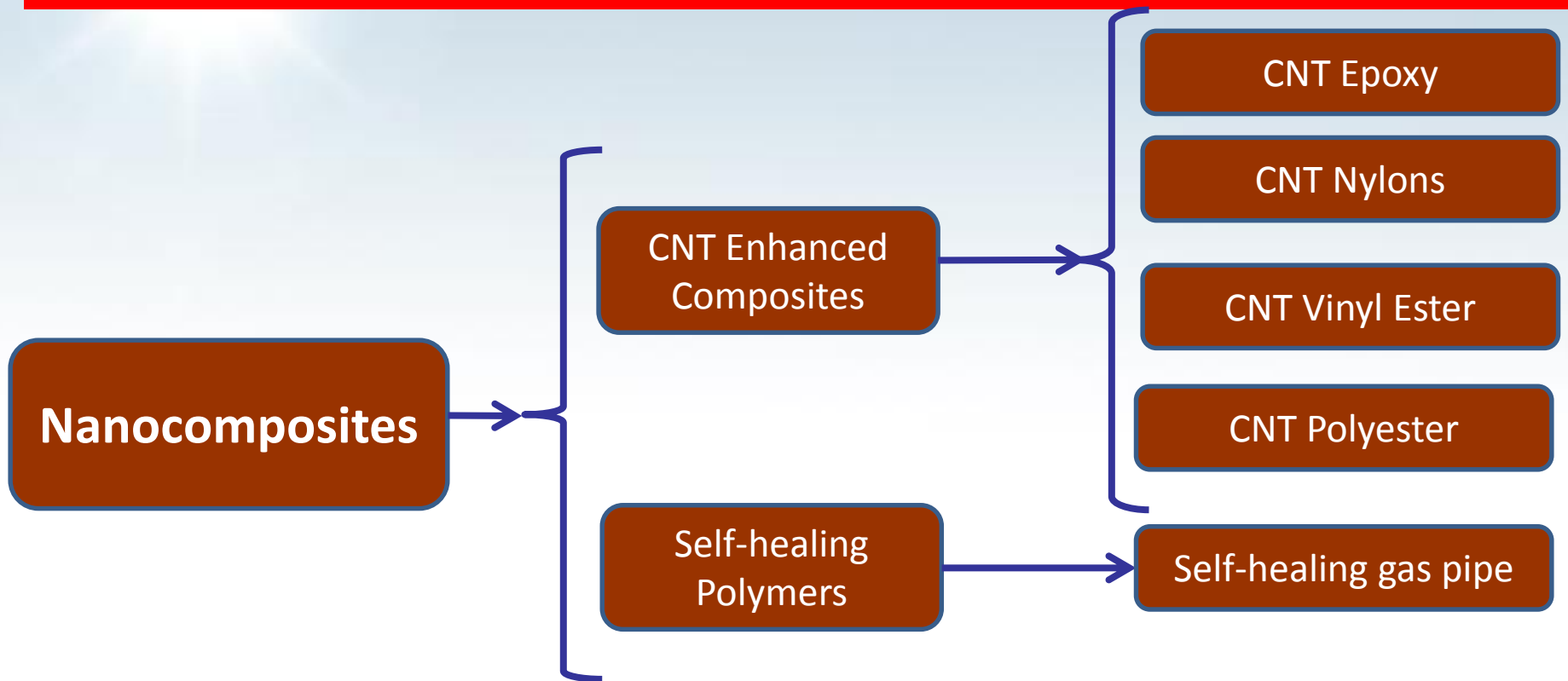


# ANI's R&D Divisions

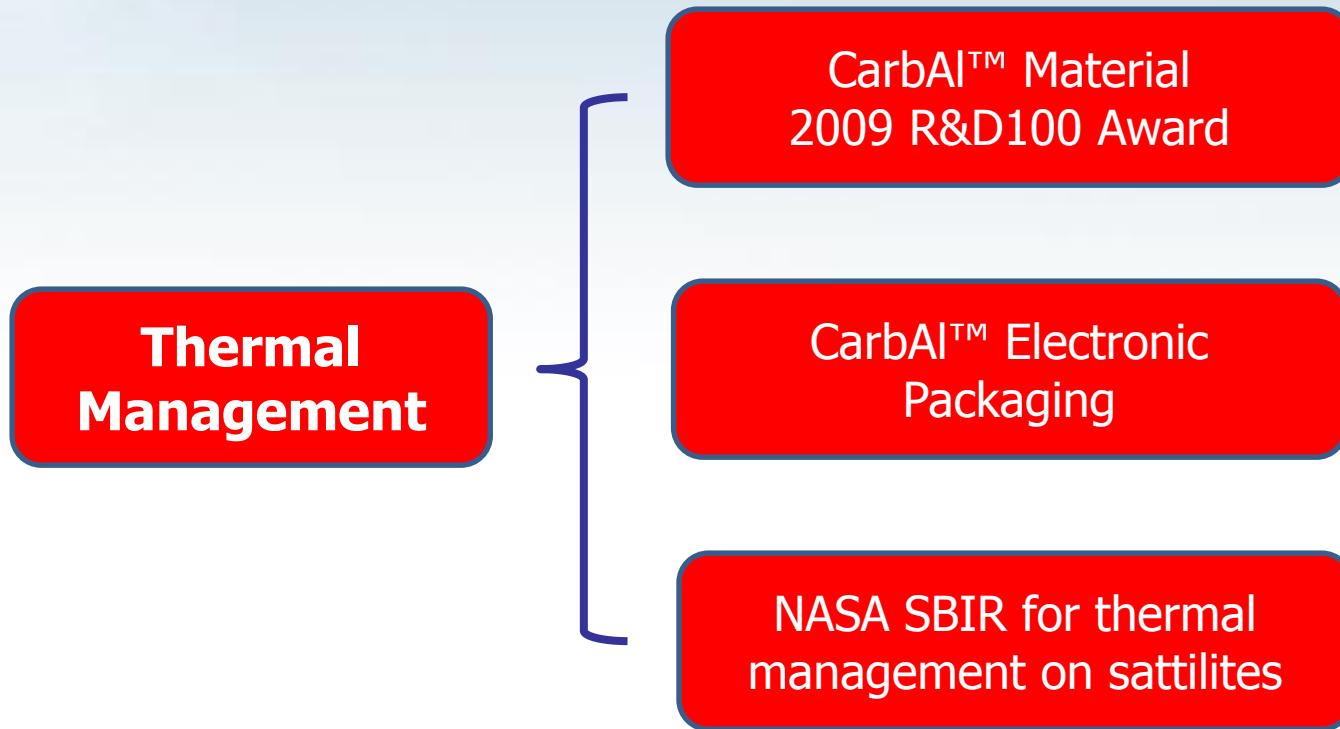
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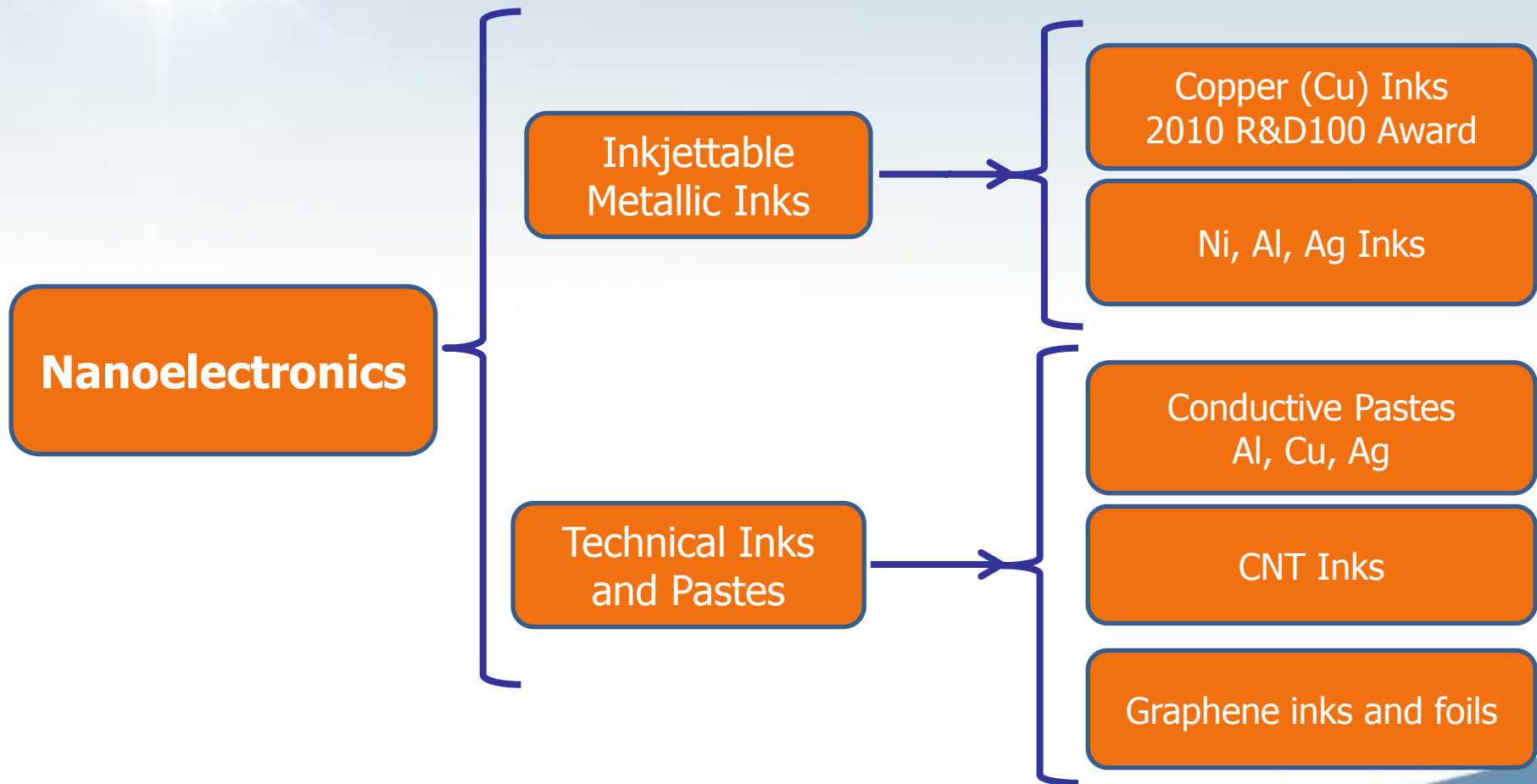
# ANI's Nanocomposites Division



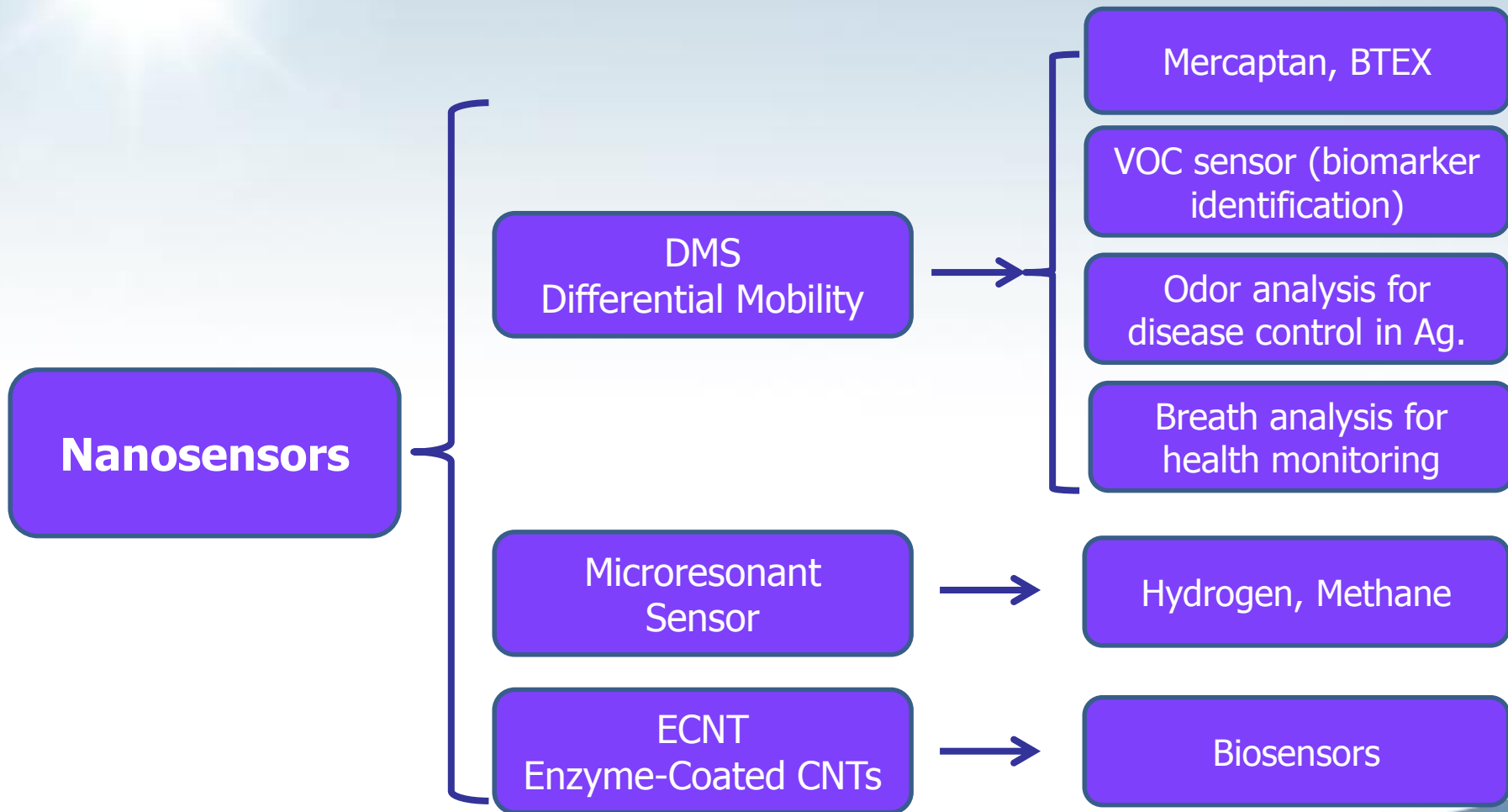
# ANI's Thermal Management Division



# ANI's Nanoelectronics Division

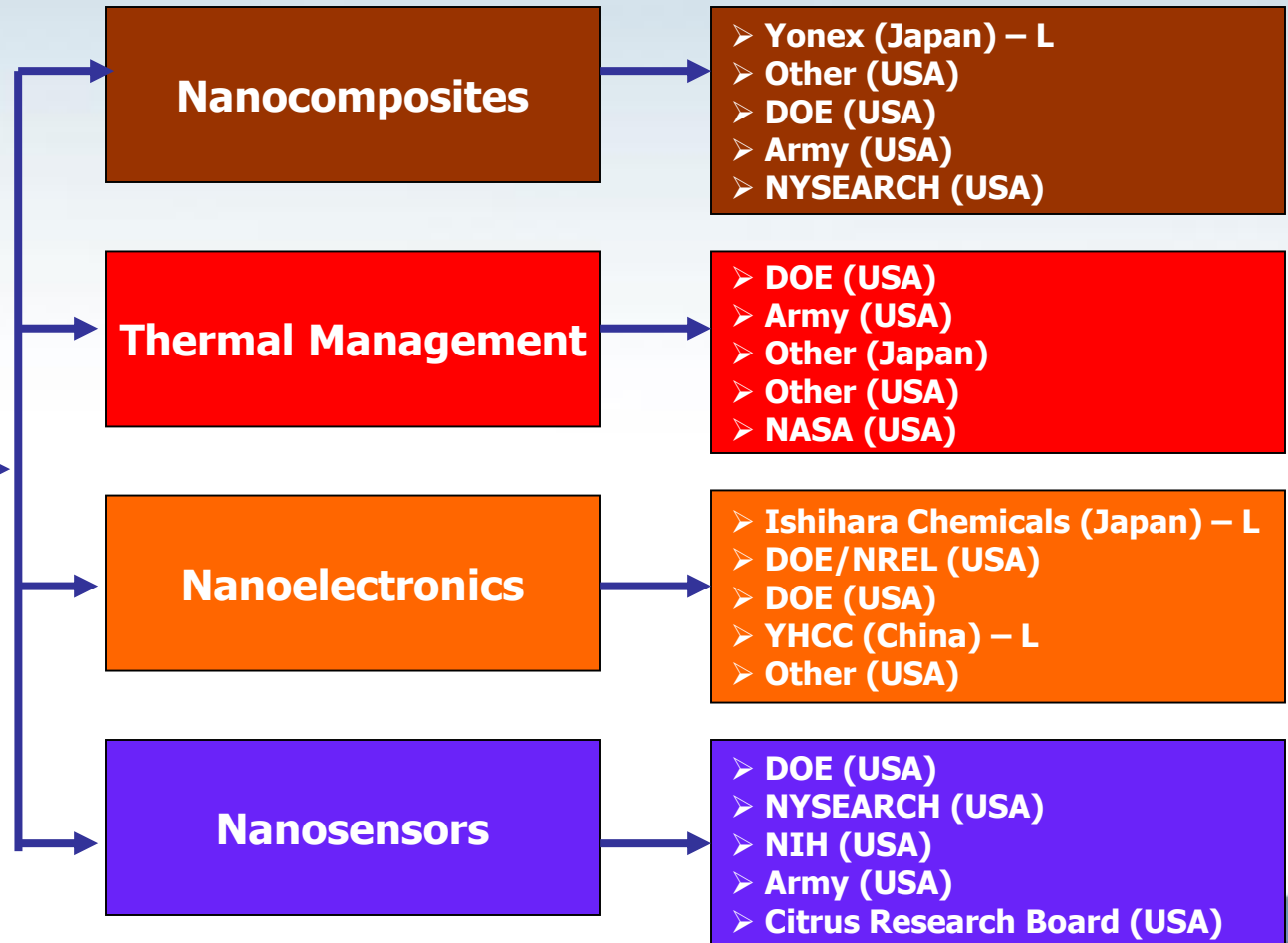


# ANI's Nanosensors Division



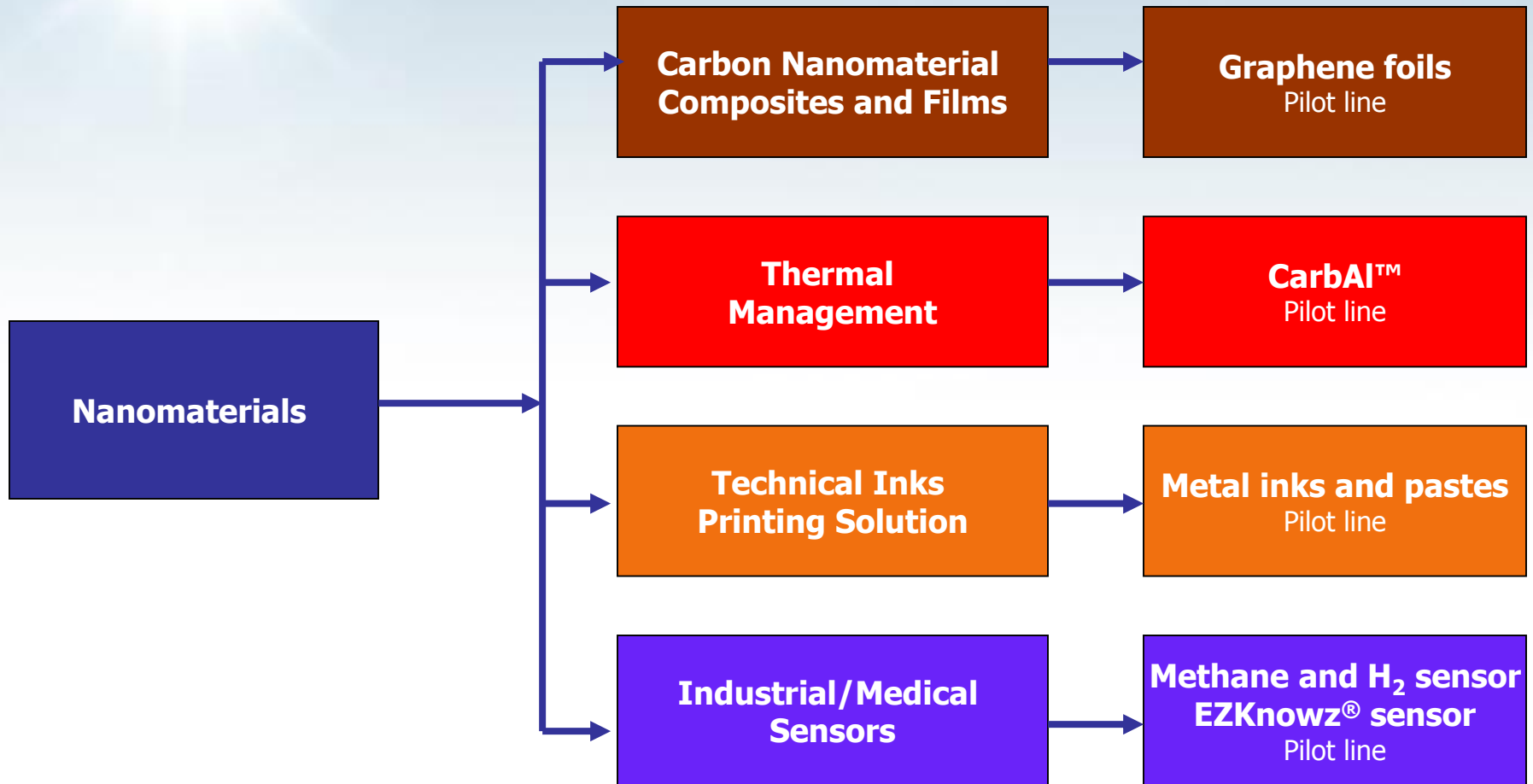


# Recent and Current Funded R&D Activities



L= licensed

# Commercialization at Applied Nanotech



# CNT Reinforced Epoxy

## Description

CNR-1-250 is a carbon nanotube loaded resin that can be cured at 250°F. The base polymer system is a multifunctional epoxy that contains <2% by weight functionalized carbon nanotubes.

## Features

- Improved flexural strength (+45%↑)
- Improved flexural modulus (+20%↑)
- Improved compression strength (+40%↑)
- Improved impact strength (+30%↑)

## Application Areas

- Sporting goods and recreation
- Automotive
- Aerospace
- Marine



*Complete set of Yonex EZONE golf clubs using ANI's CNT reinforced epoxy technology (Nanopreme™)*



*Yonex's badminton racquet (brand: VOLTRIC 80) using ANI's CNT reinforced epoxy technology (Nanopreme™)*

# NTM, Nano Thermal Management

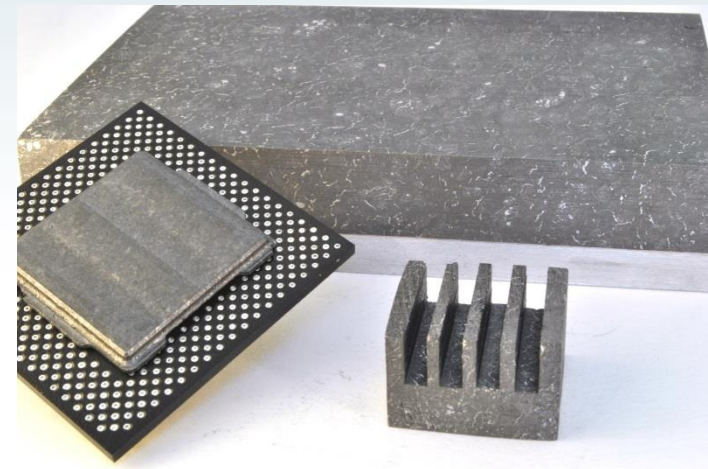


## ■ The Need

Over 55% of failures in electronic components are due to high operating temperatures.

## ■ The Solution

- CarbAI™ has been recognized as one of the 100 most significant product innovations in 2009 by R&D magazine.
- CarbAI™ composite thermal management material has a unique combination of
  - low-density (1.75 – 2.1 g/cm<sup>3</sup>)
  - high thermal diffusivity (2.9 cm<sup>2</sup>/s)
  - high thermal conductivity (350 - 450 W/mK)
  - low coefficient of thermal expansion ( $2 \times 10^{-6}$  /K)



***CarbAl™** is an advanced thermal management material composed of a porous graphitic matrix that is impregnated with a molten aluminum alloy doped with a precise amount of an additive. The resulting material is 80% carbon and 20% aluminum (and other dopants) with greater than 90% filling of the pores.*

## **Material Properties of CarbAl™**

*Thermal conductivity: 250-400 W/m-K*

*CTE:  $7 \times 10^{-6}$  /K*

*Specific heat: 0.75 J/gK*

*Specific gravity: 2.1 g/cm<sup>3</sup>*

*Bending strength: 40MPa*

*Young's modulus: 12 GPa*



## **Application Areas**

*Heat spreaders*

*PCB substrates*

*IC packaging*

*Power Electronics*

*LED substrates and housing*

*Concentrated photovoltaics*

# Production

## Overview of manufacturing process for CarbAl™

**Step 1:** Pre-heat carbon matrix, pressure mold, and aluminum

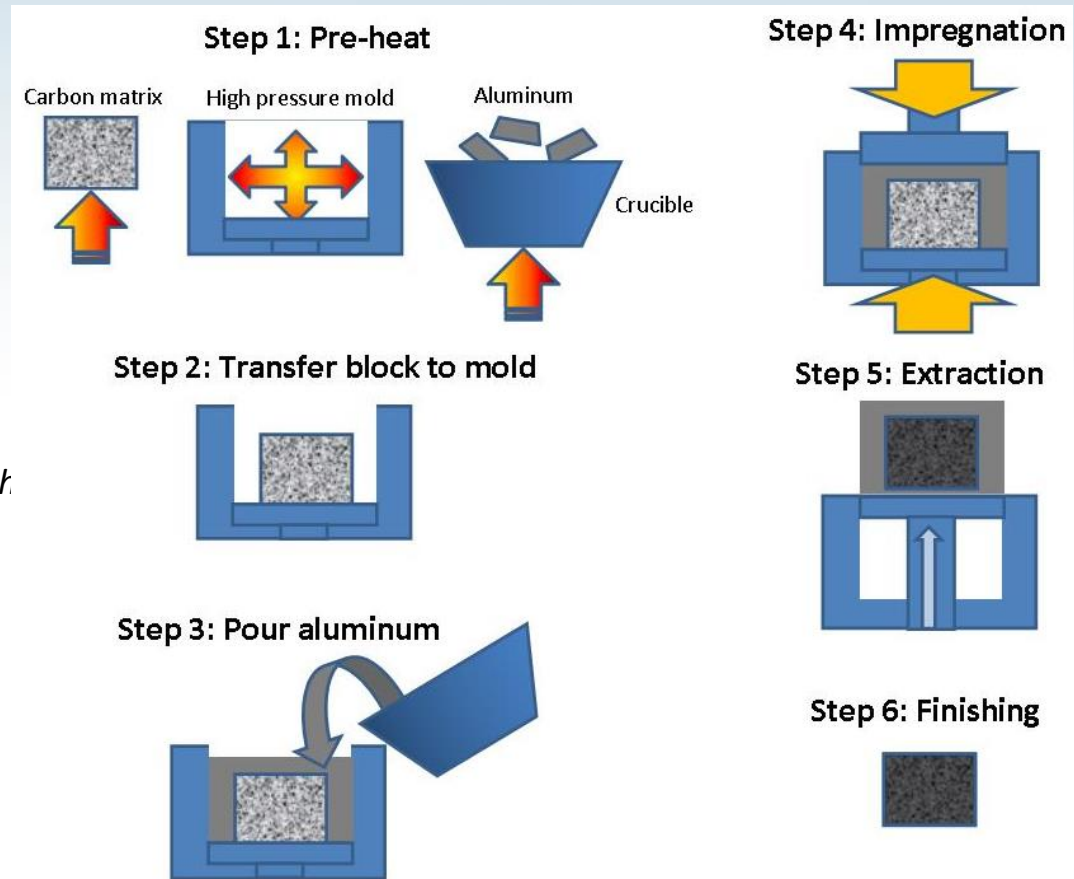
**Step 2:** Transfer heated block to heated mold

**Step 3:** Pour molten aluminum doped with additives into mold

**Step 4:** High pressure impregnation

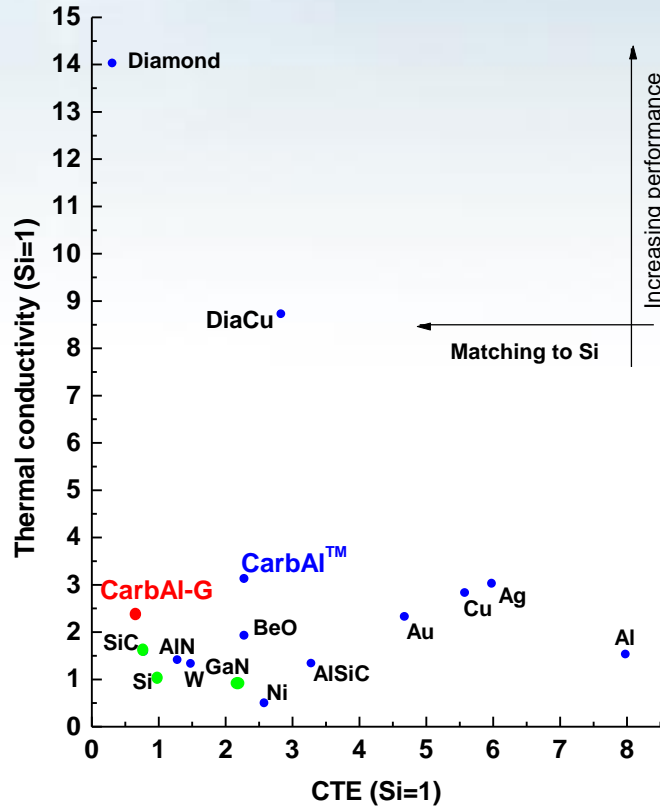
**Step 5:** Extract from mold and cooling

**Step 6:** Remove excess aluminum and finish CarbAl block

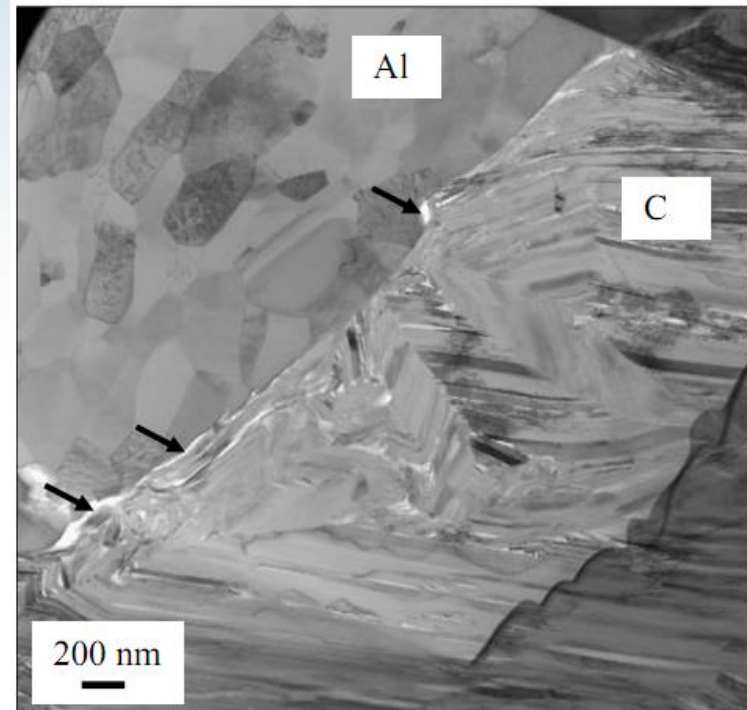




# CTE Matching to Semiconductors



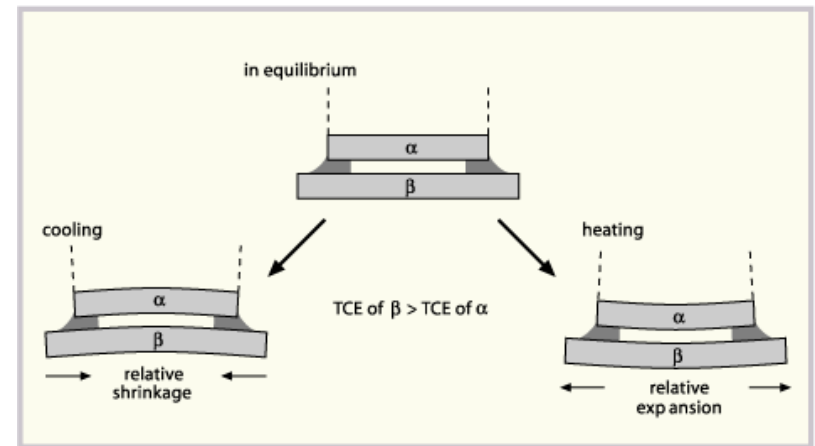
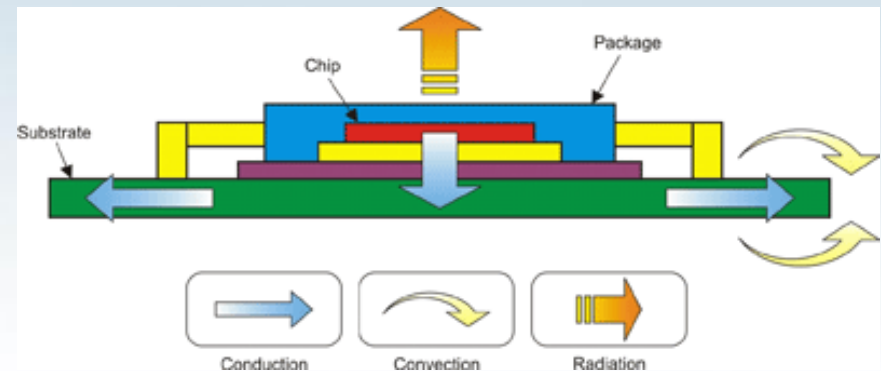
*Thermal conductivity versus CTE values*



# Description of Technology

## General Characteristics of CarbAl™

- **High thermal conductivity**
  - Graphitic planes transport thermal energy efficiently away from heat source
  - Rapid spreading of heat from the point of creation to a dissipative heat sink and active cooling
- **Low coefficient of thermal expansion (CTE)**
  - Graphite minimizes thermal expansion for semiconductor applications
  - CTE matched to materials such as silicon, gallium arsenide, and other commonly used materials to reduce stresses introduced by thermal mismatch
  - Lower CTE = less thermal stress
- **Relative Mechanical stability**
  - Aluminum filling provides mechanical support and stability
  - Compatible with standard machining processes





# Competition

CarbAl™ is a balance of key performance metrics and material properties with price of material

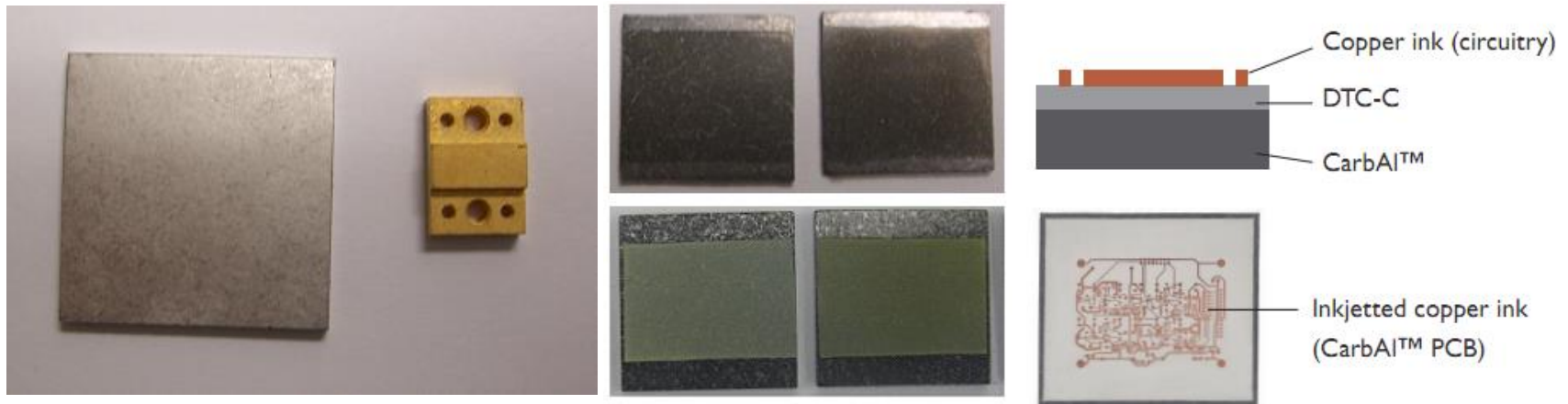
- *High thermal conductivity (amount of heat that can be transferred), 1.5x to 2x of aluminum*
- *High thermal diffusivity (speed of heat spreading), over 3x of aluminum*
- *Low coefficient of thermal expansion (amount of material expansion due to heating) more than 2x better than copper and more than 3x better than aluminum*
- *Good mechanical properties*
- *Lightweight*
- *Price is comparable to copper*

Material	Density (g/cm <sup>3</sup> )	CTE (ppm/K)	Thermal Conductivity (W/m-K)	Thermal Diffusivity (cm <sup>2</sup> /sec)	Bend Strength (MPa)	Young's Modulus (GPa)	Relative Cost
AlSiC	3	7 - 9	170 - 200	0.88	450	290	\$
CuW (10-20% Cu)	15.7-17.0	7 - 8	180 - 200		1172	367	\$\$\$
CuMo (15-20% Mo)	10	7 - 8	160 - 170			313	\$\$\$
Cu	8.96	17.8	398	1.1	330	131	\$
Al	2.7	23.6	238	0.84	137 - 200	68	<<\$
SiC	3.2	2.7	200 - 270	0.5	450	415	\$\$
AlN	3.3	4.5	170 - 200	1.47	300	310	\$\$
Beryllia	3.9	7.6	250		250	345	\$\$\$
Poco Graphite	0.9	1.02	245	-	2.7	-	\$\$
KFoam	0.48	0.69	220	0.48	2.1	-	\$\$
CVD Diamond	3.5	1 - 2	500 - 2200	10.5			\$\$\$\$\$
<b>CarbAl™-N</b>	<b>2.1</b>	<b>7</b>	<b>400-450</b>	<b>2.78</b>	<b>40</b>	<b>12</b>	<b>\$\$</b>
<b>CarbAl™-G</b>	<b>1.75</b>	<b>2.0</b>	<b>180- 400</b>	<b>2.9</b>	<b>24</b>	<b>-</b>	<b>\$</b>

# CarbAl Components

## Thercobond - Dielectric bonding material with high thermal conductivity

Surface Functionalized CarbAl™				
	Thickness ( $\mu\text{m}$ )	Breakdown Voltage (V)	Breakdown field (V/ $\mu\text{m}$ )	Thermal conductivity (W/mK)
Thercobond 1	23	2230	97	1-20
Thercobond 2	35	2480	71	1-20
Plated Ni	50	-	-	20-80
Plated Au	50	-	-	100-300



***Ni-B and Au plated CarbAl™    Dielectric layers and circuits on CarbAl™***

# NASA Phase II Technical Objectives

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## **Phase II NASA SBIR “CarbAl™ Based Thermal Management for Space Flight Systems Applications” Contract No. NNX14CC23C**

Applied Nanotech, Inc. (ANI) has developed a thermal management composite material that has a density less than aluminum, thermal properties close to copper and a coefficient of thermal expansion well matched to semiconductor materials.

**Current TRL level “6” (CarbAl components are sold commercially for non-NASA applications)**

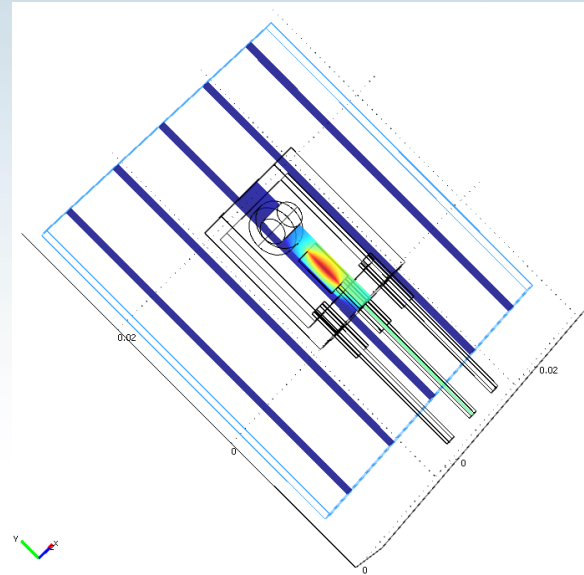
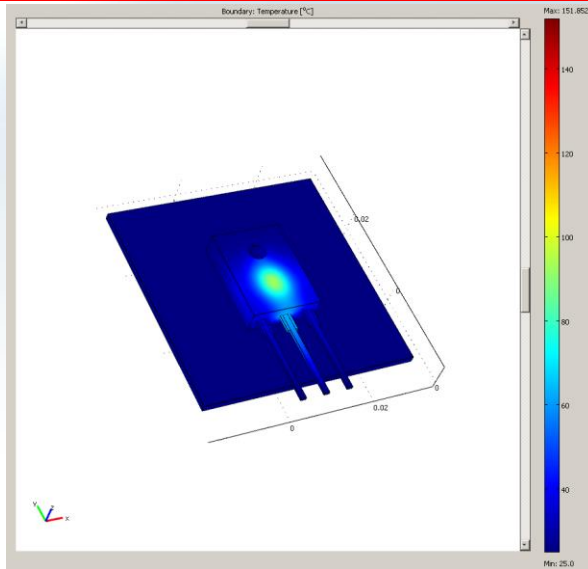
**Objective 1:** Refine Phase I thermal model for CarbAl-based thermal packaging that encompass specific thermal loads for high power transistors

**Objective 2:** Fabricate heat sink system for DC power conversion module.

**Objective 3:** Complete prototype CarbAl™ heat sink system for DC power conversion module.



# CarbAl heat sink modeling

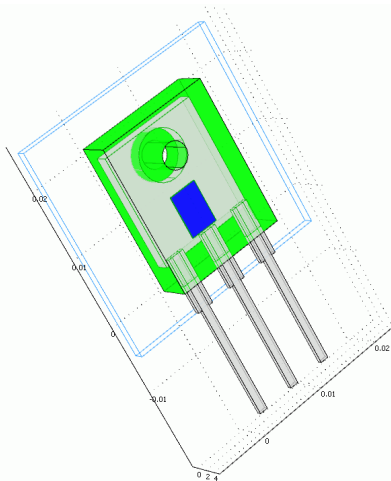


Material	Thickness, mm	k, W/mK	Density, kg/m <sup>3</sup>	Cp, J/kg·K
Aluminum	1.5	237	2700	897
CarbAl N	1.5	250/250/400	2100	750
CarbAl G	1.5	200/200/350	1750	690
Mold	3-5	0.84	1200	1200
Spreader	2	301	-	-
Leads	0.6	188	-	-
SiC	0.18; 0.36	149; k(T)	3210	670

# CarbAI modeling and Experimental results

Parameter	Specifications
Manufacturer	CREE
Transistor type	SiC MOSFET
Maximum power, W	463
Maximum current, A	90
Max junction temperature, C	150
Max bare die temp, C	150
Die dimensions, mm	4.06x6.44x0.18
Die volume, mm <sup>3</sup>	4.68
Calculated die Tmax, k=const	<b>151.9</b>
Calculated die Tmax, k=k(T)	<b>146.3</b>

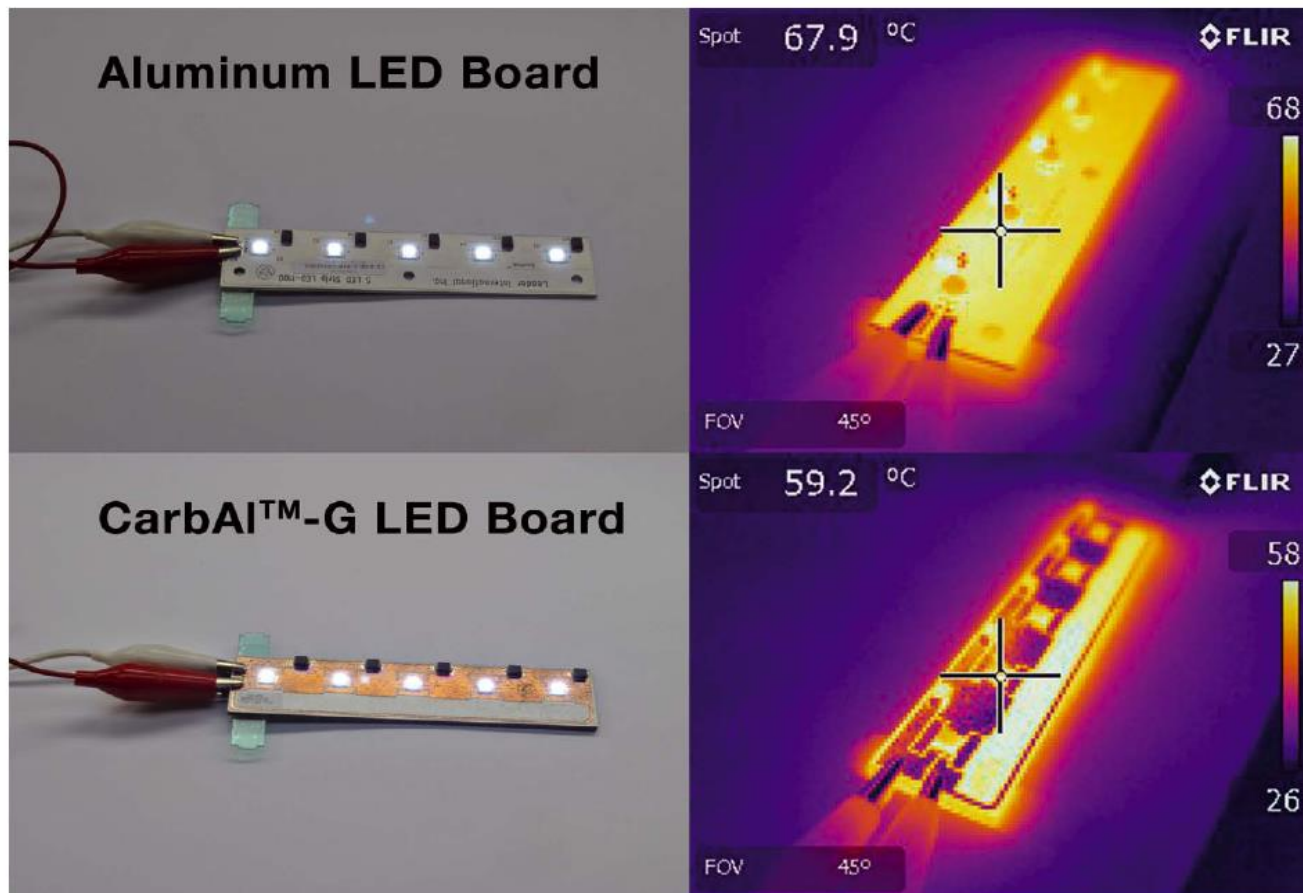
Heat sink material (k)	Max T <sub>die</sub> , C (CREE)
CarbAl N (250,250,400)	<b>151.9</b>
CarbAl N (400,250,250)	161.0
CarbAl G (200,200,350)	154.6
CarbAl G (350,200,200)	167.0
Al (237)	<b>163.0</b>



## Electric Load Tests:

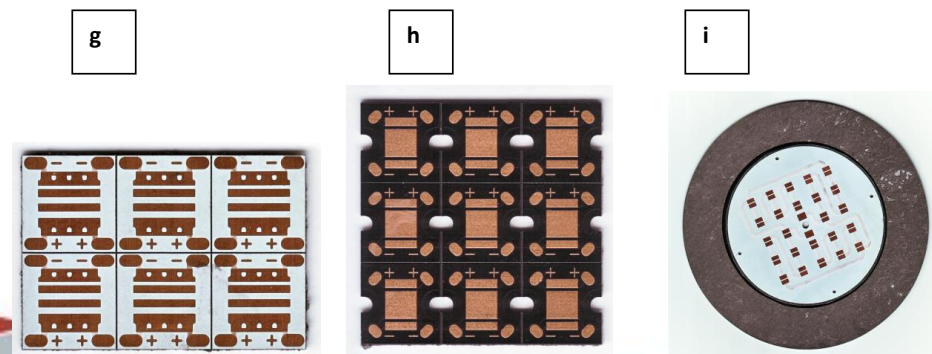
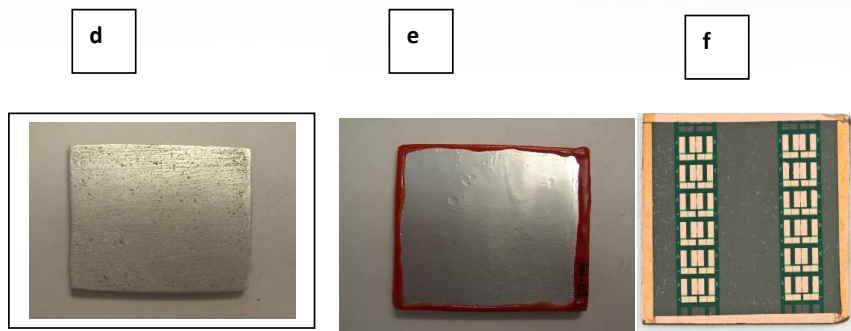
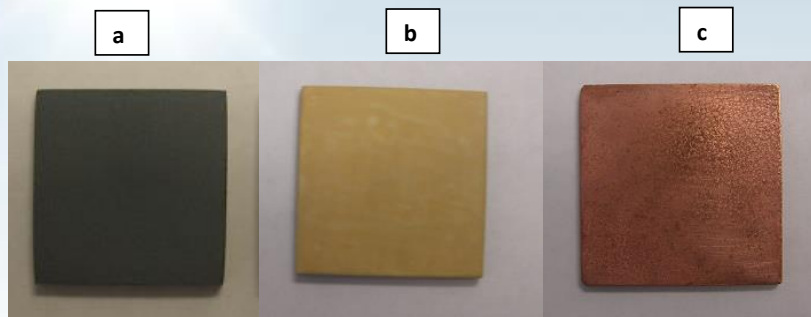
Load circuit	Gate, V	Drain current, A	Drain power, W	T <sub>block</sub> , C	T <sub>chip</sub> , C
Source	24	75	172	28.0	70.6
Source	12	68	255	27.3	85.0
Drain	12	39	565	39.5	122.0

# LED CarbAl™ Thermal Packaging





# Functionalized CarbAl™ for Various Applications



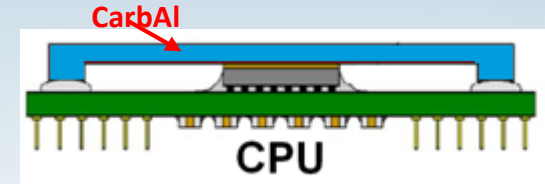
- (a) Ceramic dielectric layer on CarbAl™-G.
- (b) Polymeric dielectric layer on CarbAl™-G.
- (c) Cu plated on CarbAl™-G.
- (d) Al layer evaporated on CarbAl™-G.
- (e) Anodizes Al layer (insulating Al oxide layer) on CarbAl™-G.
- (f) Fully integrated CarbAl™-G with dielectric layers and Cu metallization for packaging 12 LEDs.
- (g) CarbAl™-G LED printed circuit board (PCB) using copper on ceramic layer.
- (h) CarbAl™-G LED printed circuit board (PCB) using copper on epoxy dielectric layer.
- (i) CarbAl™-G printed circuit board (PCB) for multiple LEDs on ceramic having a disc shape.

# Military Applications and Market Segments

## CPU Integrated Heat Spreaders



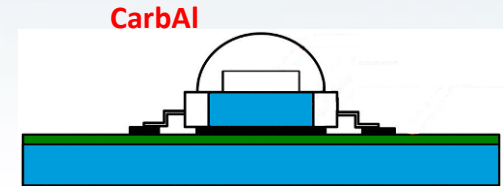
- Removes heat from hot spots on CPU processors for servers, desktops, laptops, mobile devices, and so on.
- Lids for CPU and GPU processors
- Currently use copper and aluminum lids but need better performance and CTE match as processors become faster and consume more power



## LEDs



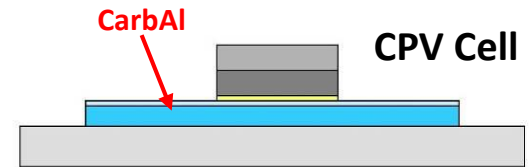
- PCBs and heat spreaders for: General lighting home and industrial, Backlights for LCD TVs, notebooks, and PC monitors, Automotive headlights and traffic signals.



## Concentrated Photovoltaics



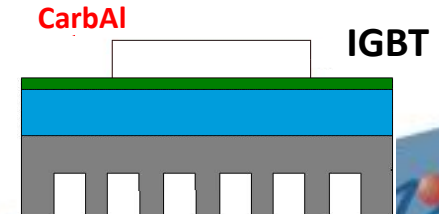
- Focus sun 100x to 1000x onto small photovoltaic cells using mirrors and lenses to increase efficiency up to 50%
- Thermal energy generated must be removed for lifetime and operating efficiency



## Power Electronics / IGBTs



- High current power electronics components in automotive, appliances, and industrial applications

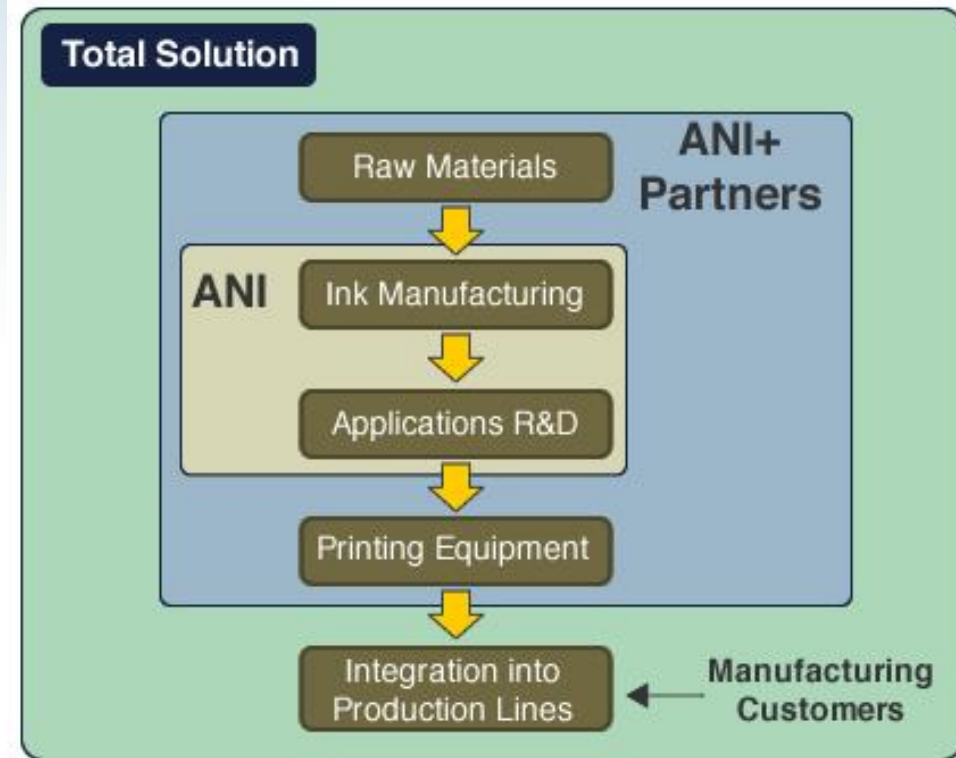




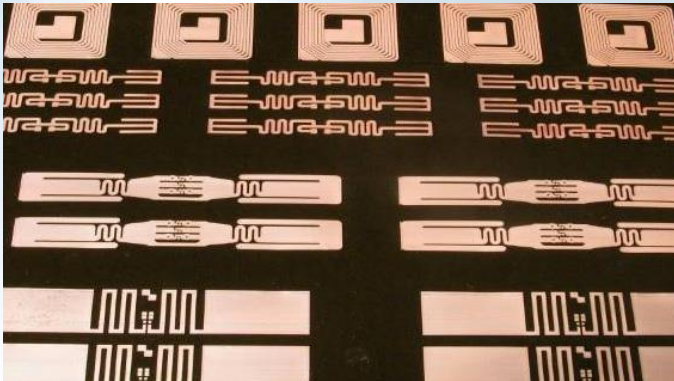
# TIPS, Technical Inks Printing Solutions



- Core technologies: technical inks/pastes and nanoparticles
- Focus on printed electronics
- Total solution approach:
  - Raw materials (nanoparticles/chemicals)
  - Ink manufacturing (formulations/dispersions)
  - Applications R&D
  - Printing equipment/processes
  - Integration into high volume production
- Total ink printing solutions are offered in collaboration with strategic partners

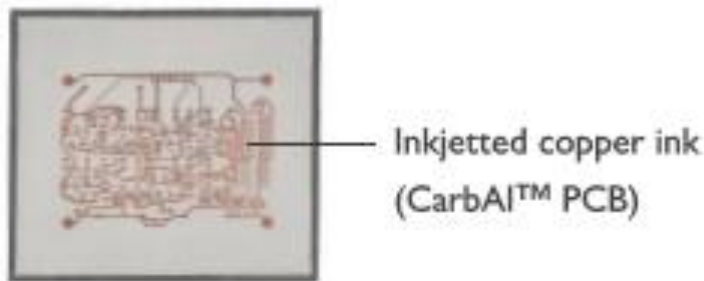
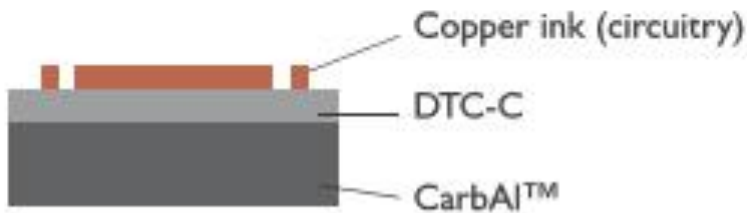
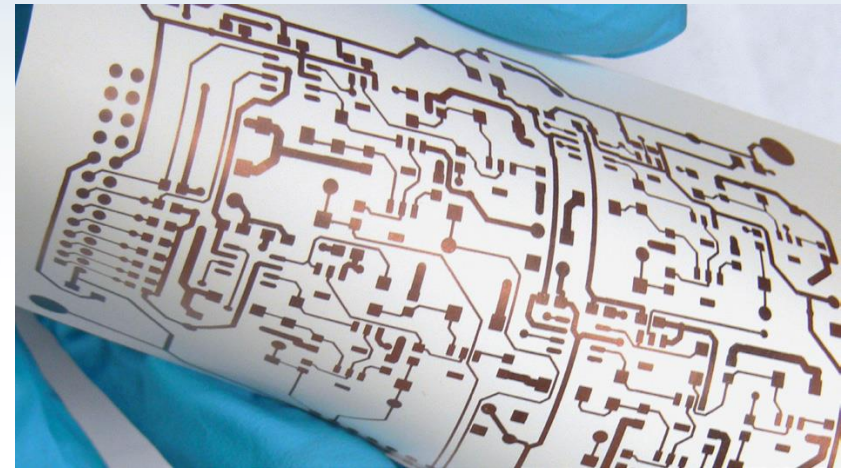


# TIPS, Technical Inks Printing Solutions



Cu inkjet printed on Kapton

Cu inkjet printed on paper



Cu inkjet printed CarbAI high thermal conductivity material with dielectric that also has high thermal conductivity

- Sensors and nanotechnology have a complementary relationship since they both rely upon molecular level phenomena.
- Our sensors have performance advantages for all "3 Ss", namely:
  - Sensitivity,
  - Selectivity,
  - Specificity.
- Our sensor research is looking at critical problems in gas sensing, including:
  - Process monitoring and monitoring of natural gas streams,
  - Homeland security,
  - Health monitoring,
  - Odor and breath analysis,
  - Forensics,
  - Agricultural pathology applications.